2818 Jul

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In fe application of:

Byeong-Hoon Lee and Seung-Keun Lee

Serial No.

09/997,080

Examiner:

Phan, Trong Q

Confirmation No.

6095

Filed:

November 28, 2001

Art Unit:

2818

For:

NONVOLATILE SEMICONDUCTOR MEMORY DEVICE

Mail Stop NON FEE AMENDMENT Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Responsive to the Office Action dated February 19, 2004, enclosed is an amendment in the above-identified application.

The fee has been calculated as shown below.

<u>CLAIMS AS AMENDED</u>					
For:	Number After Amendment	Previous Number	Extra	Rate	Additional Fee
Total Claims	22	22	0	x \$18 =	\$0
Independent Claims	5	5	0	x \$86 =	\$0
TOTAL ADDITIONAL FEE FOR THIS AMENDMENT					\$0

^{*}greater of twenty (20) or number for which fee has been paid

One replacement sheet drawing (comprises figure 3)

One annotated sheet showing changes (comprises figures 3)

Any deficiency or overpayment should be charged or credited to deposit account number 13-1703.

Respectfully submitted,

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I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450

22313-1450 Date: May 12

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^{**}greater of three (3) or number for which fee has been paid



PATENT APPLICATION
Docket No. 5484-093
Client No. PX1392-US/SSD

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Byeong-Hoon Lee and Seung-Keun Lee

Serial No. 09/997,080 Examiner: Phan, Trong Q

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MAIL STOP NON FEE AMENDMENT Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

AMENDMENT

Responsive to the Office Action, dated February 19, 2004, please amend the application as follows.

Amendments to the Drawings begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 3 of this paper.

Remarks/Arguments begin on page 8 of this paper.

An **Appendix** containing a replacement sheet for FIG. 3 is attached following page 13 of this paper.

IN THE DRAWINGS

A replacement sheet for FIG. 3 is attached in the Appendix following page 12 of this paper. The replacement sheet for FIG. 3 plainly shows that the reference numeral "100" refers only to the sector structure 100, and not to the memory cell array 101 that is contained within the sector structure 100.